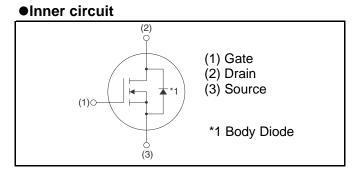


V _{DSS}	1200V
R _{DS(on)} (Typ.)	$40 \text{m}\Omega$
I _D	55A ^{*1}

Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive



Application

- Solar inverters
- DC/DC converters
- -Switch mode power supplies
- Induction heating
- Motor drives

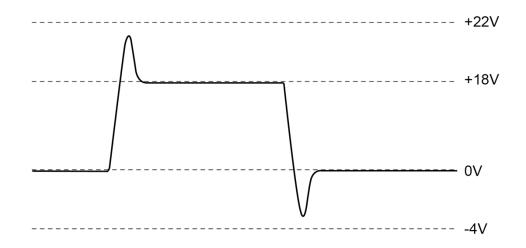
•Absolute maximum ratings $(T_a = 25^{\circ}C)$

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V _{DSS}	1200	V
Continuous drain current $T_c = 25^{\circ}C$		ا _D *1	55	А
Pulsed drain current	I _{D,pulse} *2	137	A	
Gate - Source voltage		V _{GSS}	-4 to 22	V
Gate-Source Surge Voltage		V_{GSS_surge}	-4 to 22	V
Recommended Drive Voltage		$V_{GS_{op}}$	0 / 18	V
Junction temperature		Т _ј	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 1mA$	1200	-	-	V
		$V_{DS} = 1200V, V_{GS} = 0V$				
Zero gate voltage drain current	I _{DSS}	T _j = 25°C	-	1	10	μA
		T _j = 150°C	-	2	-	
Gate - Source leakage current	I_{GSS^+}	$V_{GS} = +22V, \ V_{DS} = 0V$	-	-	100	nA
Gate - Source leakage current	I _{GSS-}	$V_{GS} = -4V, V_{DS} = 0V$	-	-	-100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_{D} = 10mA$	2.7	-	5.6	V
		$V_{GS} = 18V, I_{D} = 20A$				
Static drain - source on - state resistance	$R_{DS(on)}$ *3	T _j = 25°C	-	40	50	mΩ
		T _j = 125°C	-	60	-	
Gate input resistance	R _G	f = 1MHz, open drain	-	7	-	Ω

•Example of acceptable Vgs waveform



•Electrical characteristics ($T_a = 25^{\circ}C$)

Doromotor	Symbol	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	${\sf g}_{\sf fs}$ *3	$V_{DS} = 10V, I_{D} = 20A$	-	8.3	-	S
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	1337	-	
Output capacitance	C _{oss}	V _{DS} = 800V	-	76	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	27	-	
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 600V	-	122	-	pF
Turn - on delay time	t _{d(on)} *3	$V_{DD} = 400V, I_{D} = 18A$	-	21	-	
Rise time	t _r *3	V _{GS} = 18V/0V	-	39	-	20
Turn - off delay time	t _{d(off)} *3	$R_L = 22\Omega$	-	49	-	ns
Fall time	t _f *3	$R_{G} = 0\Omega$	-	24	-	
Turn - on switching loss	${\sf E_{on}}^{*3}$	$V_{DD} = 600V, I_{D} = 20A$ $V_{GS} = 18V/0V$	-	283	-	
Turn - off switching loss	${\sf E_{off}}^{*3}$	$R_G = 0\Omega L=250\mu H$ *E _{on} includes diode reverse recovery	-	118	-	μJ

•Gate Charge characteristics ($T_a = 25^{\circ}C$)

Parameter	Symbol Conditions	Conditions	Values			Unit
		Min.	Тур.	Max.	Unit	
Total gate charge	Q_g^{*3}	$V_{DD} = 600V$	-	107	-	
Gate - Source charge	Q _{gs} ^{*3}	I _D = 20A	-	22	-	nC
Gate - Drain charge	Q_{gd}^{*3}	V _{GS} = 18V	-	41	-	
Gate plateau voltage	V _(plateau)	$V_{DD} = 600V, I_{D} = 20A$	-	9.6	-	V

*1 For T_j =175°C and thermal dissiparion to ambience of 165W or more. Limited only by maximum temperature allowed.

*2 PW \leq 10 $\mu s,$ Duty cycle \leq 1%

*3 Pulsed

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Sumbol	Conditions	Values			Unit	
Faranielei	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Inverse diode continuous, forward current	ا _S *1	T _c = 25°C	-	-	55	А	
Inverse diode direct current, pulsed	I _{SM} *2	T _c = 25 0	-	-	137	А	
Forward voltage	V_{SD} *3	$V_{GS} = 0V, I_{S} = 20A$	-	3.2	-	V	
Reverse recovery time	t _{rr} *3		-	25	-	ns	
Reverse recovery charge	Q _{rr} *3	I _F = 20A, V _R = 600V di/dt = 1100A/μs	-	115	-	nC	
Peak reverse recovery current	I _{rrm} ^{*3}		-	9	-	А	

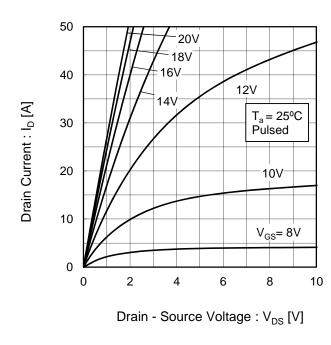
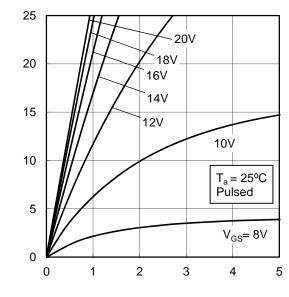


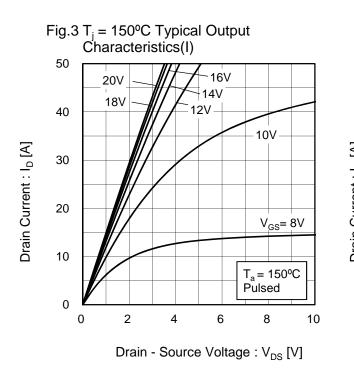
Fig.1 Typical Output Characteristics(I)

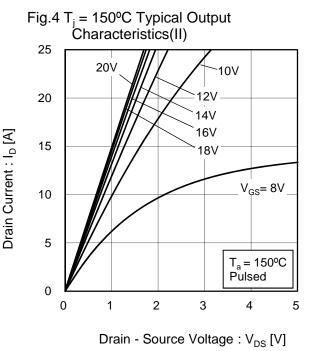
Fig.2 Typical Output Characteristics(II)



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]





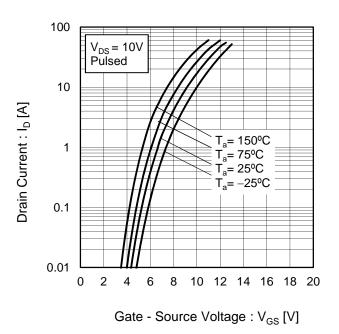


Fig.5 Typical Transfer Characteristics (I)

Fig.6 Typical Transfer Characteristics (II)

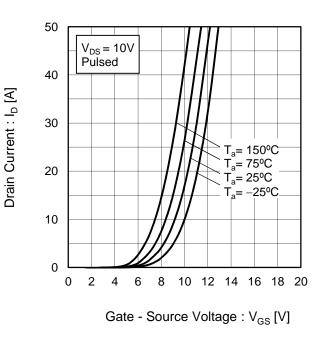
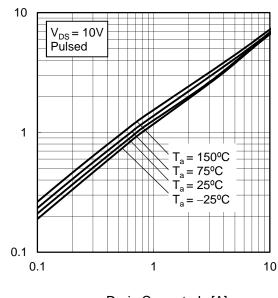
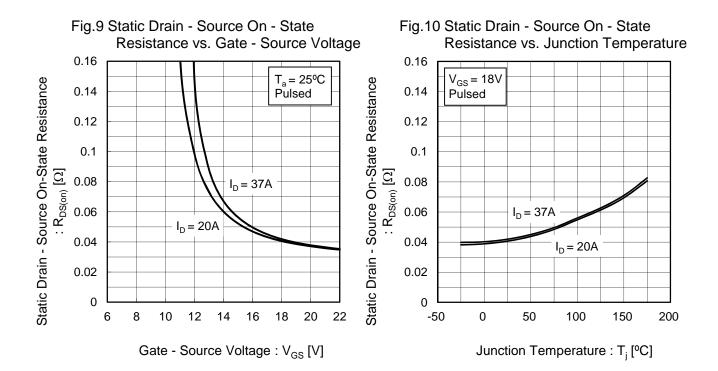


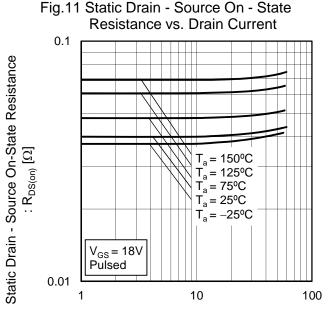
Fig.7 Gate Threshold Voltage vs. Junction Temperature 6 10 $V_{DS} = 10V$ $I_D = 10 \text{mA}$ 5 Gate Threshold Voltage : V _{GS(th)} [V] Transconductance : g_{fs} [S] 4 3 1 2 1 0.1 0 0.1 -50 0 50 100 200 150 Junction Temperature : T_i [°C]

Fig.8 Transconductance vs. Drain Current



Drain Current : I_D [A]





Drain Current : I_D [A]

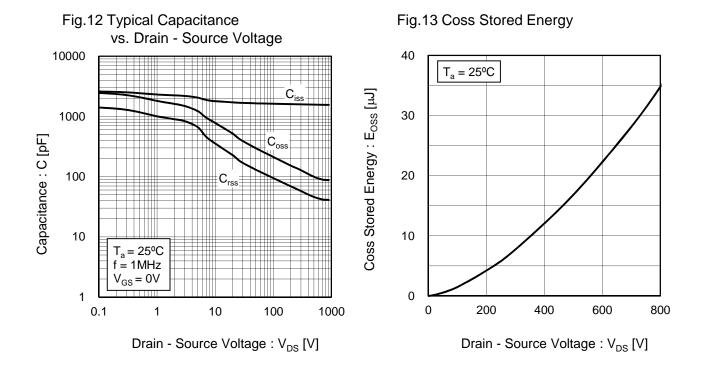


Fig.14 Switching Characteristics

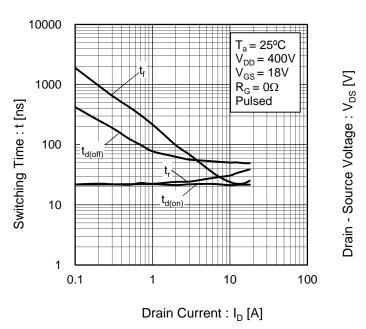
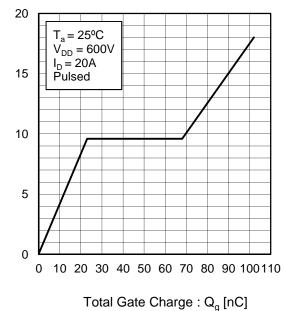
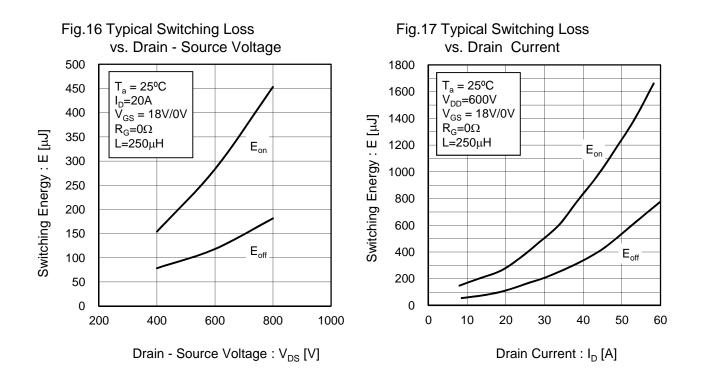
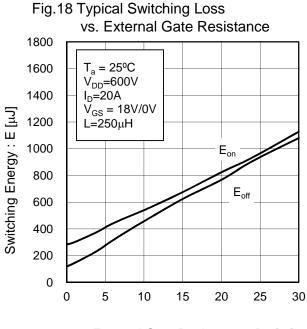


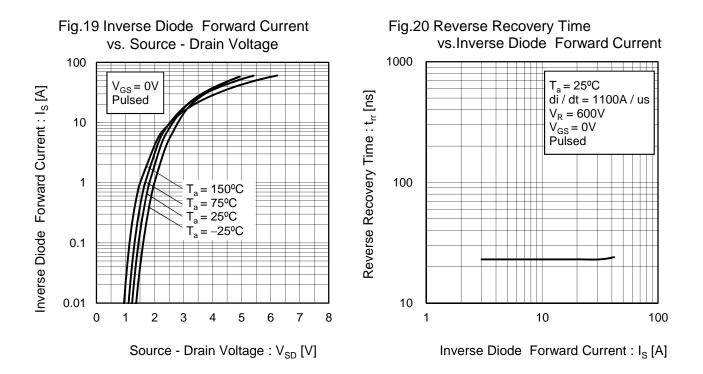
Fig.15 Dynamic Input Characteristics







External Gate Resistance : $R_G [\Omega]$



Measurement circuits

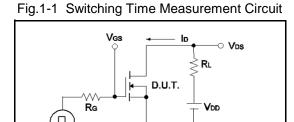


Fig.2-1 Gate Charge Measurement Circuit

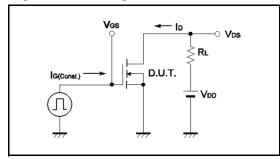


Fig.3-1 Switching Energy Measurement Circuit

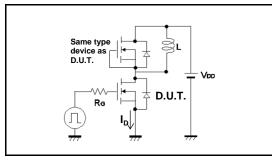


Fig.4-1 Reverse Recovery Time Measurement Circuit Fig.4-2 Reverse Recovery Waveform

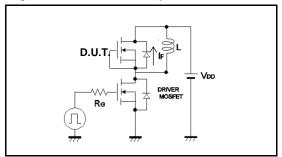


Fig.1-2 Switching Waveforms

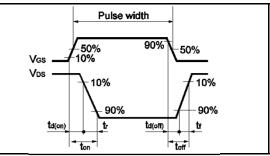


Fig.2-2 Gate Charge Waveform

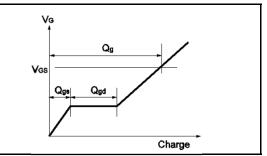
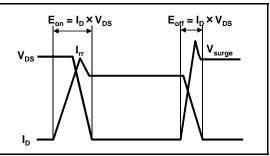
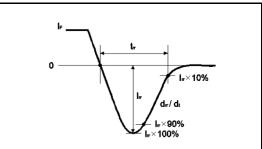


Fig.3-2 Switching Waveforms







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